

SHANGHAI SUNRISE ELECTRONICS CO., LTD.

SS22 THRU SS26

SURFACE MOUNT SCHOTTKY **BARRIER RECTIFIER**

TECHNICAL SPECIFICATION

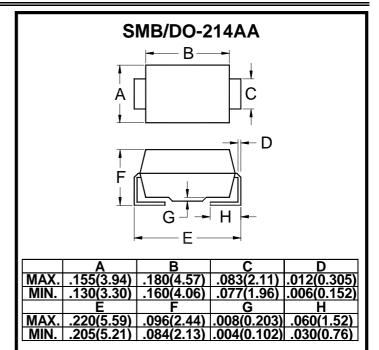
VOLTAGE: 20 TO 60V CURRENT: 2.0A

FEATURES

- · Ideal for surface mount pick and place application
- Low profile package
- Low power loss, high efficiency
- High current capability, low V_F
- High surge capability
- High temperature soldering guaranteed: 260°C/10sec/at terminal

MECHANICAL DATA

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

derate carrent by 2070)							
RATINGS	SYMBOL	SS22	SS23	SS24	SS25	SS26	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	V
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	V
Maximum Average Forward Rectified Current (T _L =100°C)	l _{F(AV)}	2.0					А
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I _{FSM}	50					А
Maximum Instantaneous Forward Voltage (at rated forward current)	V _F	0.5 0.7			.7	V	
Maximum DC Reverse Current $T_a=25^{\circ}$	C ,	0.5					mΑ
(at rated DC blocking voltage) T _a =100°		10.0					mA
Typical Junction Capacitance (Note 1) C _J	200					pF
Typical Thermal Resistance (Note 2	$R_{\theta}(ja)$	25					°C/W
Storage and Operation Junction Temperature	T_{STG},T_{J}	-65 to +150					°C
Note:							

- 1.Measured at 1.0 MHz and applied voltage of 4.0V_{dc}
- 2. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area